

12-Bit, Current Output, Complete High Speed D/A Converter

AD565

1.0 <u>SCOPE</u>

This specification documents the detailed requirements for Analog Devices space qualified die including die qualification as described for Class K in MIL-PRF-38534, Appendix C, Table C-II except as modified herein.

The manufacturing flow described in the STANDARD DIE PRODUCTS PROGRAM brochure at <u>http://www.analog.com/aerospace</u> is to be considered a part of this specification.

This data sheet specifically details the space grade version of this product. A more detailed operational description and a complete data sheet for commercial product grades can be found at www.analog.com/AD565

2.0 <u>Part Number</u>. The complete part number(s) of this specification follow:

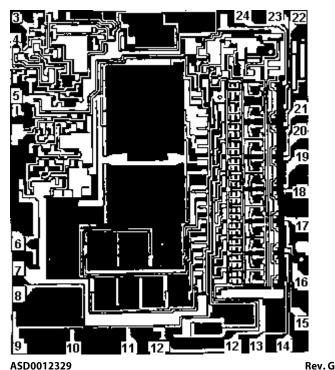
Part NumberDescriptionAD565-000C12-Bit, Current Output, Complete High Speed D/A Converter

3.0 Die Information

3.1 Die Dimensions

Die Size	Die Thickness mil	Bond Pad Metalization		
119 mil x 146 mil	19 mil \pm 2 mil	Al/Cu		

3.2 Die Picture



BIT 1 IN (MSB) NC 1 24 NC 2 BIT 2 IN 23 V_{CC} 3 BIT 3 IN 22 REF OUT (+10V ±1%) 4 21 BIT 4 IN AD565A REF GND 5 BIT 5 IN 20 TOP VIEW BIT 6 IN REF IN 6 19 (Not to Scale) -V_{EE} 7 18 BIT 7 IN BIPOLAR OFFSET IN 8 17 BIT 8 IN DAC OUT (-2mA F.S.) 9 BIT 9 IN 16 10V SPAN R 10 15 BIT 10 IN 20V SPAN R 11 14 BIT 11 IN PWR GND 12 13 BIT 12 IN (LSB) NC = NO CONNECT

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3.3 Absolute Maximum Ratings. 1/

V _{CC} to power ground	0 to +18V dc
V _{EE} to power ground	0 to -18V dc
Voltage on DAC output (pin 9)	3V dc to +12V dc
Digital inputs (pins 13 to 24) to power ground	1.0V dc to +7.0V dc
Ref in to ref ground	±12V dc
Bipolar offset to reference ground	±12V dc
10V span R to reference ground	±12V dc
20V span R to reference ground	±24V dc
Ref out	Indefinite short to power ground
	momentary short to V _{CC}
Power dissipation	1000 mW
Storage temperature range	
Operating temperature range	55°C to +125°C
Junction temperature (T _J)	+150°C

<u>1</u>/ Stresses above the absolute maximum rating may cause permanent damage to the device. Extended operation at the maximum levels may degrade performance and affect reliability.

3.4 <u>Recommended operating conditions.</u>

Positive supply voltage (V _{CC})	+15V
Negative supply voltage (V _{EE})	15V
Operating ambient temperature range	55°C to +125°C

4.0 <u>Die Qualification</u>

In accordance with class-K version of MIL-PRF-38534, Appendix C, Table C-II, except as modified herein.

- (a) Qual Sample Package Sidebrazed DIP
- (b) Qual Sample Size and Qual Acceptance Criteria 10/0
- (c) Pre-screen electrical test over temperature performed post-assembly prior to die qualification.

5.0 **Dice Electrical Characteristics**

Table I						
Parameter Symbol		Conditions Note 1	Limit Min	Limit Max	Units	
Relative Accuracy	RA	All bits w/ positive errors on All bits w/ negative errors on		±0.5	LSB	
Differential Nonlinearity	DNL	Major transition		±0.75	LSB	
Gain Error	AE	$R_{REF} = 50 \cdot fixed$		±0.25	% of FS	
Offset Error	Vos			±0.05	% of FS	
Bipolar Zero Error Note 2	B _{PZE}	$R_{BO} = 50 \cdot fixed$		±0.15	% of FS	
Reference Output Voltage	V _{REF}	Note 3	9.90	10.10	V	
Output Current	Іоит —	Unipolar (all bits on)	-1.6	-2.4	mA	
Output Current		Bipolar (all bits on)	-0.8	-1.2	IIIA	
Dower Supply Dejection Datio	PSRR	$V_{s} = +11.4V \text{ to } +16.5V \text{ dc}$		±10.0	PPM of FRS/%	
Power Supply Rejection Ratio		$V_{\rm S}$ = -11.4V to -16.5V dc		±25.0		
Power Supply Current	lcc			+5.0		
Note 4, 5	I _{EE}			-18.0	mA	
Power Dissipation	PD			345.0	mW	
Digital Input High Voltage	VIH		2.0	5.5	V	
Digital Input Low Voltage	VIL			0.8	V	
Digital Input High Current	Ін	$V_{IH} = 5.5V$		300.0	μΑ	
Digital Input Low Current	lı∟	$V_{IL} = 0V$		100.0	μA	

Table I Notes:

 $1. \qquad V_{CC} = +15V, \, V_{EE} = -15V, \, V_{IH} = 2.0V, \, V_{IL} = 0.8V, \, T_A = 25^{\circ}C.$

2. MSB on, all other bits off.

3. The reference output is loaded with 0.5mA reference input current, 1.0mA bipolar offset current, and 1.5mA additional current.

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Electrical Characteristics for Qual Samples 5.1

Table II							
Parameter	Symbol	Conditions Note 1	Sub- groups	Limit Min	Limit Max	Units	
Relative Accuracy	RA	All bits w/ positive errors on All bits w/ negative errors on	1		±0.5	LSB	
		, in bits wy negative enois on	2, 3		±0.75		
Differential Nonlinearity	DNL	Major transition	1		±0.75	LSB	
Gain Error	AE	$R_{REF} = 50 \cdot fixed$	2, 3		±1.0 ±0.25	% of FS	
			1 1		±0.25		
Gain Error Temperature Coefficient	TCA _E		2, 3		±30.0	ppm of FS/°C	
Offset Error	Vos		1		±0.05	% of FS	
Offset Error Temperature Coefficient	TCVos		2, 3		±2.0	ppm of FS/°C	
Bipolar Zero Error Note 2	B _{PZE}	$R_{BO} = 50 \cdot fixed$	1		±0.15	% of FS	
Bipolar Zero Error Temperature Coefficient Note 2	TCB _{PZE}		2, 3		±10.0	ppm of FS/°C	
Reference Output Voltage Note 3	V_{REF}		1, 2, 3	9.90	10.10	V	
Reference Output Current Note 4	IREF		1	1.5		mA	
Output Current	Іоит	Unipolar (all bits on) Bipolar (all bits on)	- 1 -	-1.6 -0.8	-2.4 -1.2	mA	
Power Supply Rejection Ratio	PSRR	$V_s = +11.4V$ to $+16.5V$ dc	1		±10.0	PPM of FRS/%	
	1 5111	$V_{\rm S}$ = -11.4V to -16.5V dc			±25.0		
Power Supply Current Note 4, 5	Icc I _{EE}		1 -		+5.0 -18.0	mA	
Power Dissipation	PD		1		345.0	mW	
Digital Input High Voltage	VIH		1	2.0	5.5	V	
Digital Input Low Voltage	VIL		1		0.8	V	
Digital Input High Current	Iн	V⊪ = 5.5V	1		300.0	μΑ	
Digital Input Low Current	١	$V_{\text{IL}}=0V$	1		100.0	μΑ	

Table II Notes:

 V_{CC} = +15V, V_{EE} = -15V, V_{IH} = 2.0V, V_{IL} = 0.8V.
MSB on, all other bits off.
In subgroup 1, the reference output is loaded with 0.5mA reference input current, 1.0mA bipolar offset current, and 1.5mA additional current. In subgroup 2 and 3, only the 0.5mA reference input current is applied. The reference must be buffered to supply external loads at elevated temperatures.

4. Guaranteed for +11.4 \leq V_{CC} \leq +16.5V.

Guaranteed for $-11.4 \le V_{EE} \le -16.5V$. 5.

6.0 Delta Parameter Table

Table III								
Demonstern	Symbol	Sub- groups	Post Burn In Limit		Post Life Test Limit		Life Test	
Parameter			Min	Max	Min	Max	Delta	Units
Gain Error	A _E	1		±0.25		±0.30	±0.05	% of FS
Bipolar Zero Error	B _{PZE}	1		±0.15		±0.225	±0.075	% of FS

7.0 Life Test/Burn-In Information

- 7.1 HTRB is not applicable for this drawing.
- 7.2 Burn-in is per MIL-STD-883 Method 1015 test condition B or C.
- 7.3 Steady state life test is per MIL-STD-883 Method 1005.

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Rev	Description of Change	Date	
Α	Initiate	June 26, 2001	
В	Update web address. Fix footer	Jan. 25, 2002	
С	Update web address.	Aug. 5, 2003	
D	Update header/footer & add to 1.0 Scope description.	Feb. 26, 2008	
E	Add Absolute Maximum Ratings table in section 3.3	April 2, 2008	
F	Updated Section 4.0c note to indicated pre-screen temp testing being performed.	June 6, 2009	
G	Updated Fonts and Sizes to ADI standard, enlarged die picture pad numbering	22-Sept-2011	

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